

MIT OpenCourseWare
<http://ocw.mit.edu>

6.334 Power Electronics
Spring 2007

For information about citing these materials or our Terms of Use, visit: <http://ocw.mit.edu/terms>.

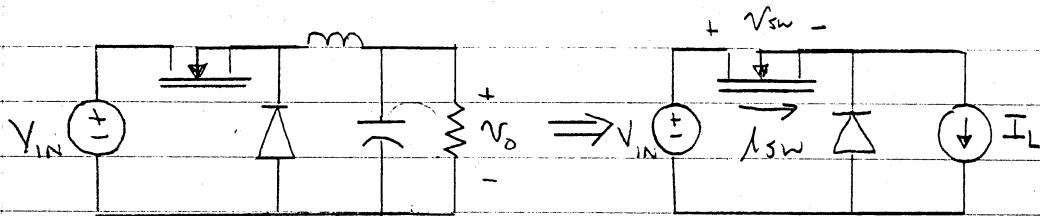
Power Electronics Notes - D. Perreault

Notes: Reading KSTV Chapter 24

★★ Switching Losses and snubbers

* Semiconductor Losses (Back of the Envelope)

Example: Buck converter w/ MOSFET

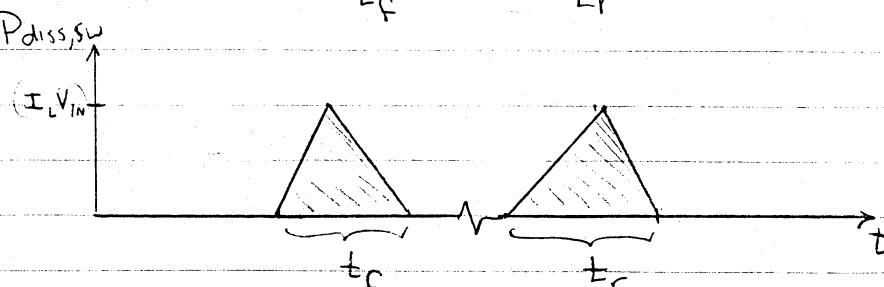
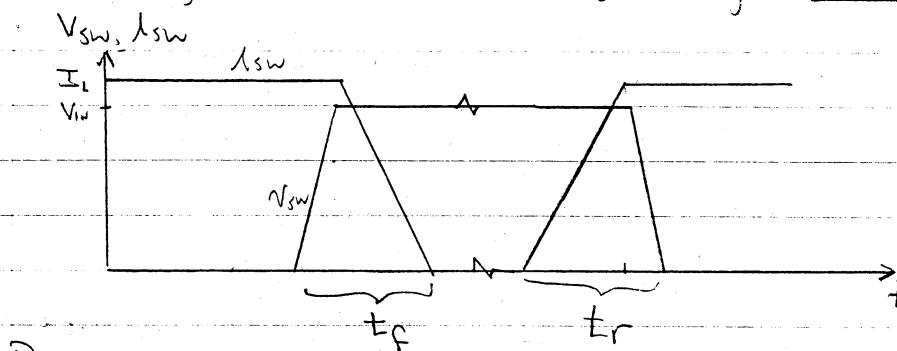


Conduction losses

$$\text{Fet (resistive)} \quad P_{\text{FET,CONO}} = I_{\text{RMS}}^2 R_{\text{ds,ON}} \approx (I_L^2 D) R_{\text{ds,ON}}$$

$$\text{Diode (const drop)} \quad P_d, \text{con,1} = \langle \text{V}_{\text{diode}} \rangle V_{\text{d,ON}} \approx (I_L D') V_{\text{d,ON}}$$

Switching Losses (Zoom in on switching) \rightarrow back of the envelope only!



Turn OFF of FET

current falls After voltage rises (diode must turn on before cur. falls)

t_f governed by device params + gate drive

Turn on of FET

current rises before voltage falls (diode must conduct until switch carries whole current)

t_r governed by device params + gate drive

Linear transitions are a rough approximation!

\Rightarrow other losses (e.g. diode rev. rev.) also exist

$$P_{\text{switch,sw}} \approx \left(\frac{1}{2} t_f V_{\text{in}} I_L + \frac{1}{2} t_r V_{\text{in}} I_L \right) f$$

$$= \frac{1}{2} V_{\text{in}} I_L (t_f + t_r) f$$

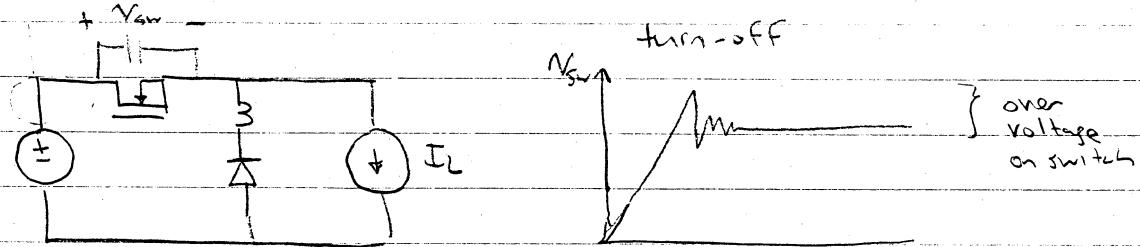
Power Electronics Notes - D. Perreault

⇒ major switching loss component $\propto f$. we want $f \uparrow$ so L, C size ↓ but losses limit us.

Other Issues

- we want to switch fast ($\downarrow t_f, t_r$) but other factors exist:

→ Parasitics + Overshoots



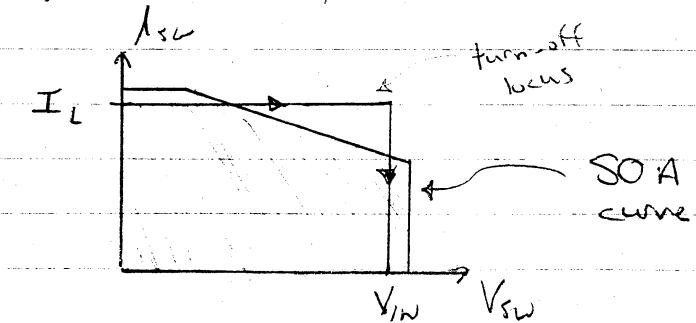
→ EMI

- high $\frac{dI}{dt}, \frac{dV}{dt}$ lead to EMI, + affects control circuits
 $(\frac{dV}{dt} \rightarrow$ Capacitive coupling, $\frac{dI}{dt} \rightarrow$ Inductive coupling)

→ Safe Operating Area

Some devices have limitations on simultaneous voltage + current applied instantaneously (BJT's, GTO's, MCT's)

Can operate at I_L and can operate at V_{IN} , but NOT AT SAME TIME

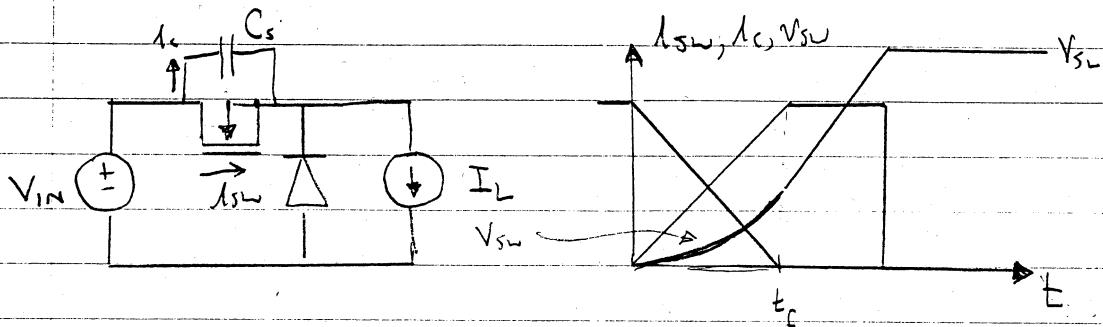


→ Also, some devices have $\frac{dI}{dt}$ or $\frac{dV}{dt}$ limits (esp. thyristor type devices)

Power Electronics Notes - D. Perreault

- ★ Snubbers :
 - 1.) Control switching locus
 - 2.) Lower the internal device dissipation

If Capacitor across device during turn-off

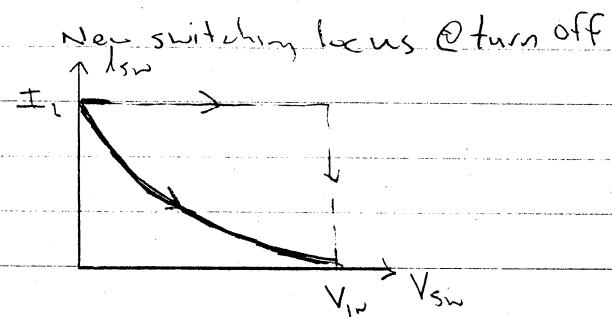
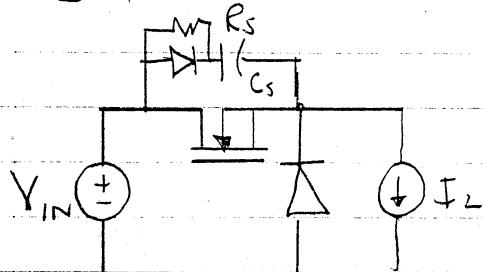


I_L diverted through C_S while switch turns off.

Reduced V -rise across switch during turn off \rightarrow lower switch losses

★ But there will be a big problem when the switch turns on!!

∴ Simple RCD turn off snubber



During turn-off, same as above

$$\text{As calculated on the next page: } W_{\text{turn-off,sn}} \approx \frac{I_L^2 t_f^2}{24 C_S}$$

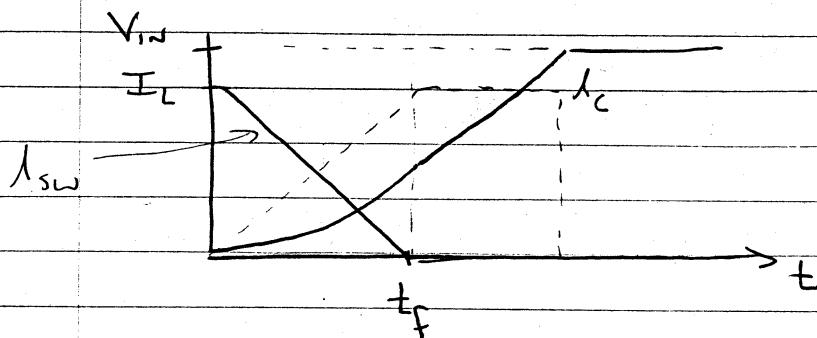
During turn-on, dissipate C_S energy in R_S $W_{es} = \frac{1}{2} C_S V_{IN}^2$

(Note: Need a min duty ratio to do this!)

Snubber reduces device switching loss, but increases total dissipation. (typically, this depends on device capacitance)
 → definitely more loss if device capacitance exceeds "natural" capacitance

To size snubber, trade P_{device} , P_{es} , $\frac{dV}{dt}$ vs A_A , min duty cycle.

Power Electronics Notes - D. Perreault



The turn-off loss + capacitor charging can be calculated as follows:

$$I_{sw}(t) = I_L \left(1 - \frac{t}{t_f}\right) \quad 0 < t < t_f$$

$$I_C = I_L \left(\frac{t}{t_f}\right) \quad 0 < t < t_f$$

$$V_{sw} = \frac{1}{C} \int_0^t I_C(t) dt = \frac{I_L}{2C t_f} t^2 \quad 0 < t < t_f$$

$$\begin{aligned} \therefore E_{sw,off} &= \int_0^{t_f} V_{sw} I_{sw} dt = \int_0^{t_f} \frac{I_L^2}{2C t_f} \left(t^2 - \frac{t^3}{t_f}\right) dt \\ &= \frac{I_L^2}{6C} t_f^2 - \frac{I_L^2}{8C} t_f^2 \end{aligned}$$

$E_{sw,off} = \frac{I_L^2 t_f^2}{24C}$

With no capacitance, we would get

$$E_{loss} = \frac{1}{2} I_L V_{IN} t_f$$

$$V_{pk} @ \text{sw. turn off } \frac{I_L}{2C} t_f \quad (\text{assumed } < V_{IN})$$

$$E_{stored} (\text{in capacitor}) = \frac{1}{2} C V_{IN}^2$$

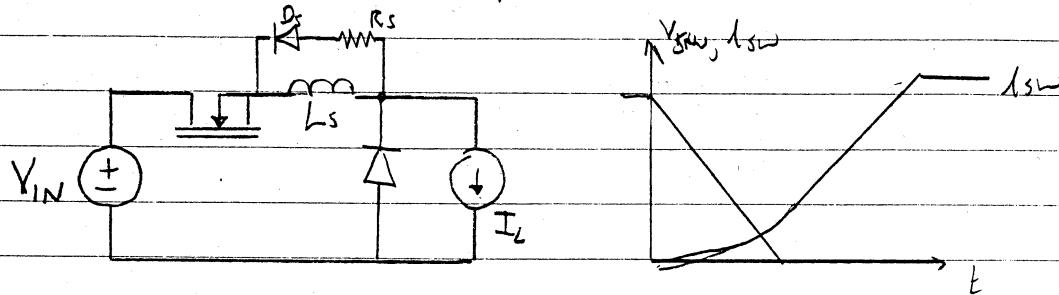
$$\text{This is } \geq \frac{1}{2} C \frac{\frac{I_L^2 t_f^2}{2C}}{4C^2} = \frac{I_L^2 t_f^2}{8C}$$

$\frac{V_{pk}^2}{2} e$
sw. off point

∴ The stored energy in C is much larger than the switch transition loss.

Power Electronics Notes - D. Perreault

Similar snubbing can be implemented for turn on



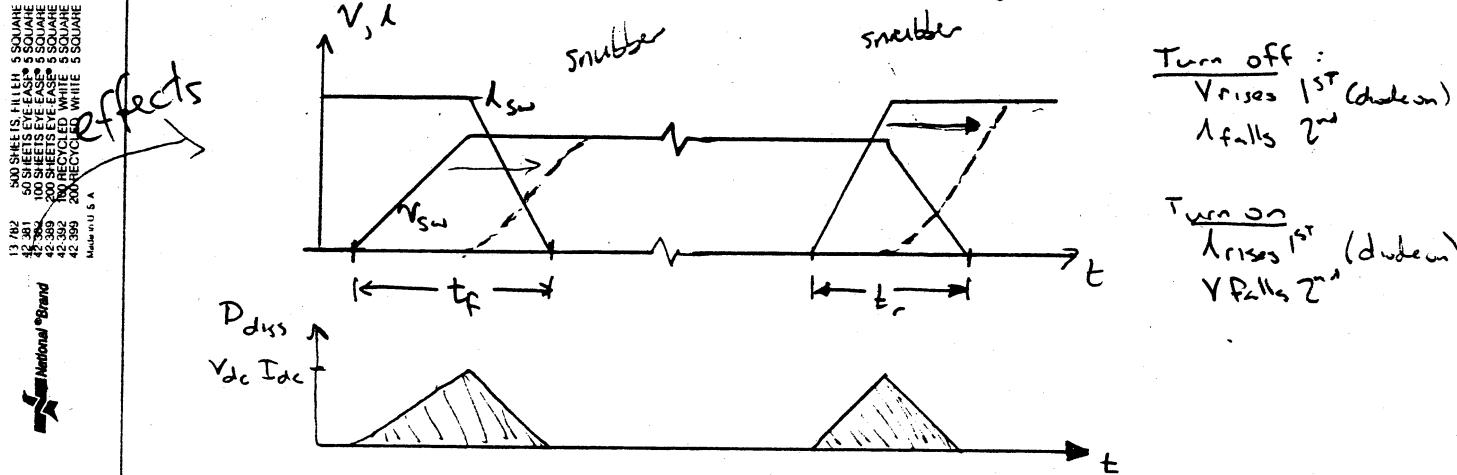
- reduced switch, diode loss
- increased total loss (incl. R_s)
- controlled switching losses ($SOA, \frac{dI}{dt}$)

* Note: Snubber reset implies max duty ratio and imposes an overvoltage on the switch!!!

ZCS/ZVS Techniques, dc-dc converter applications

REVIEW: (put initial stuff on board before class)

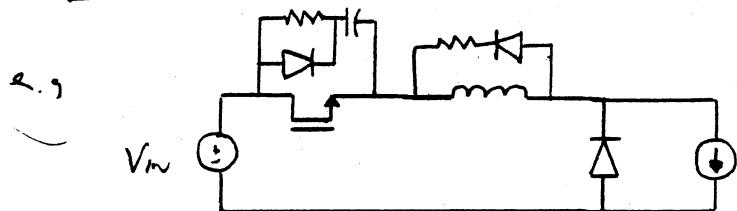
The switching transitions in conventional PWM converters generate losses due to the nature of the V, I waveforms during the transitions.



This has 3 deleterious effects:

1. Achievable f_{sw} & efficiency limited
2. EMI due to fast $dI/dt, dV/dt \Rightarrow$ NOISE
3. Switching losses may exceed SOA

Last time: SNUBBERS MITIGATE THESE EFFECTS, BUT ADD LOSSES

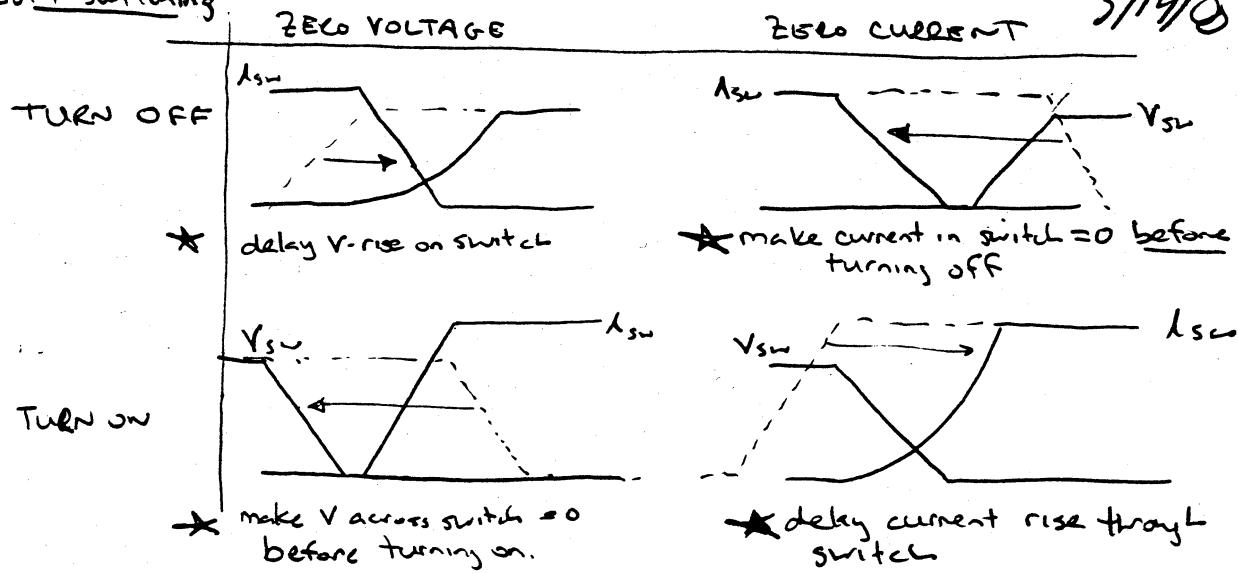


Today: Soft-Switching techniques try to mitigate these effects without adding substantial losses.

GENERAL METHODS: Zero-Voltage Switching (ZVS)
Zero-Current Switching (ZCS)

Can be applied to both turn-on and turn-off

These techniques typically require additional circuitry &/or control complexity &/or additional conduction losses. But, the trade may be worth it...

Soft switching

⇒ The turn-off snubber from before acts like ZVS turn off (in limit)
 ⇒ The turn-on snubber from before acts like ZCS turn on (in limit)
 but are not lossless or quasi-lossless.

⇒ Note: Varying degrees of "softness" exist, depending on the degree to which waveform rises are delayed, and waveform slopes near transitions (additional categorizations exist.)

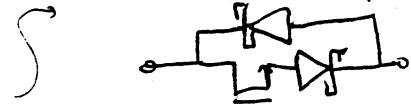
Notes on ZCS QR Buck (SEE HANDOUT / OVERHEAD)

Example #1: ZCS Quasi-Resonant Buck Converter

Explain operational Cycle

Man switch turns on ZCS
 MAIN switch/Diode turns off ZCS
 Diode turns on ZCS
 Diode turns off ZCS

Alt sw/diode impl.



Explain: V_{out} control by f_{sw} control / Pulse density modulation

Explain: Exper. waveforms @ light, heavy loads.

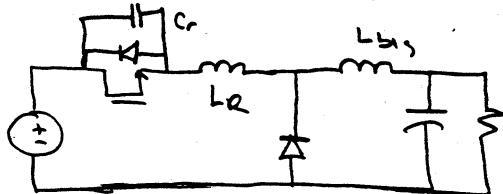
Adv: Smooth, soft waveform transitions
 low switching losses to moderately high frequencies

Disadv: ZCS turn on loses junction cap energy
 High conduction losses (converted to PWM) due to resonant action
 & energy sloshing about (→ half-wave version)
 diode voltage rating 2x.
 requires frequency control over very wide range

3-14-00

Other versions of this technique exist (Half-wave, ZVS version) and for many converter types (boost, buck-boost, Cuk, sepic, etc.)

ex/ ZVS Half-wave QR buck converter



Final Aside: This converter type is forced to use frequency control to achieve soft switching. (which has its disadvantages). We are very used to duty ratio (or fixed-frequency PWM) control, but there are actually many methods:

ex/ Fixed freq PWM
Frequency control
Phase-shift control
Phase control (ac systems)
and more... → show full-bridge example
to demo alternative methods

$$\boxed{f_{\text{sw}}}$$

Next example: Suppose we want to retain PWM Control. We can do this (at a price)

ZVS PWM Buck Converter Example

Extra circuitry & control (+ increased device ratings) to allow soft-switched operation.

Explain operational cycle + duty ratio control approach

Main SW : ZVS turn on, ZVS turn off

Aux SW : ZVS/ZCS turn on, ZVS turn off

Diode : ZVS turn on, (poor) ZCS turn off

Advantages: Duty ratio control of main switch (over a range) (PWM)
low loss on main & aux switch @ turn on/off
junction cap on main sw is part of C_R (no turn-on loss)

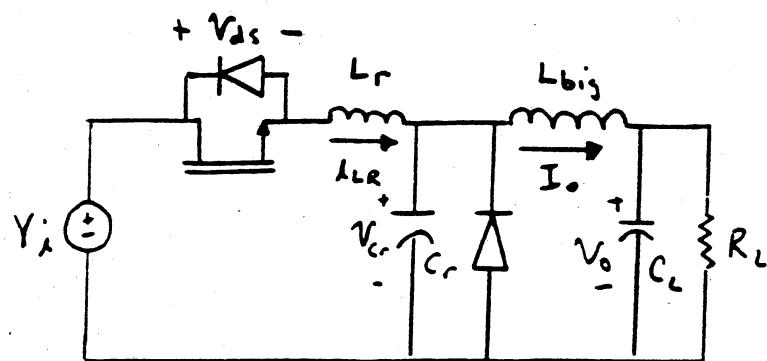
Disadvantages: Very high voltage rating on main switch (varies w/ load)
additional switch & control circuitry → complexity
only limited reduction of diode losses at turn off

Other versions of this approach exist (i.e. ZCS, other topologies)

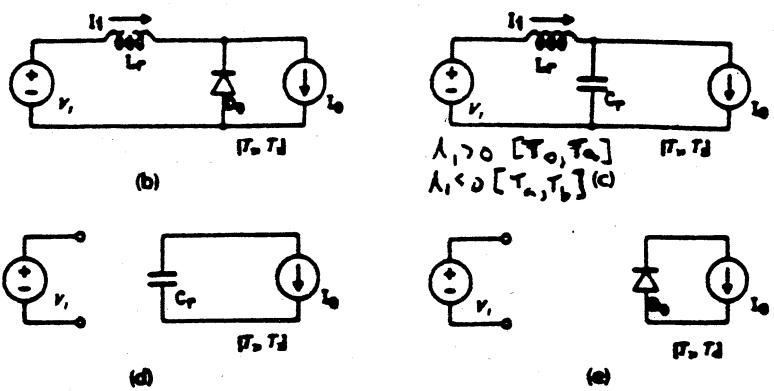
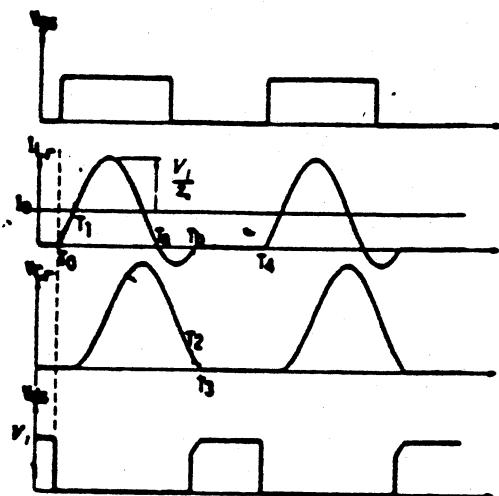
Many other soft-switching approaches exist, some with PWM control (ex / Zero-Voltage Transition Circuits), and some with other methods (ex / phase-shift full bridge, resonant converters, etc.)

Next time: More soft switching techniques. We will focus on popular methods for bidirectional converters and inverters (esp 3 Φ). Esp focus on RPI, AECP, RDCL topologies.

Full-Wave ZCS Quasi-Resonant Buck Converter

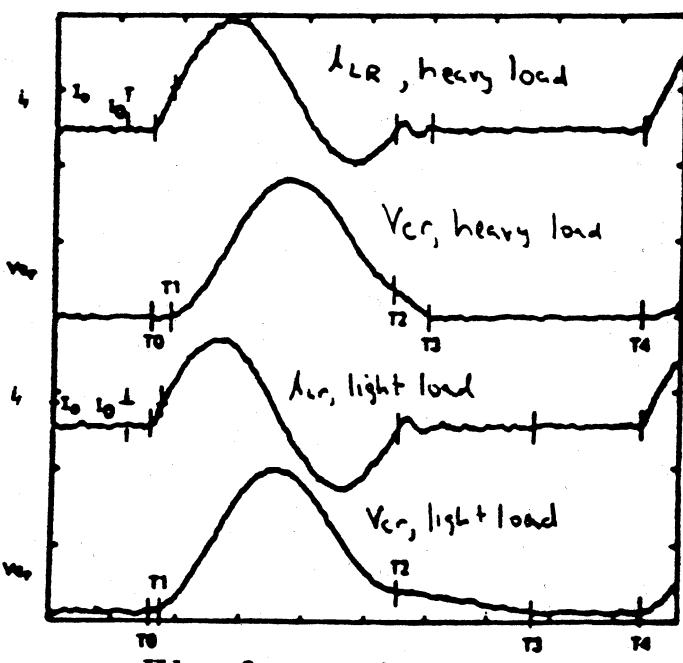


Converter

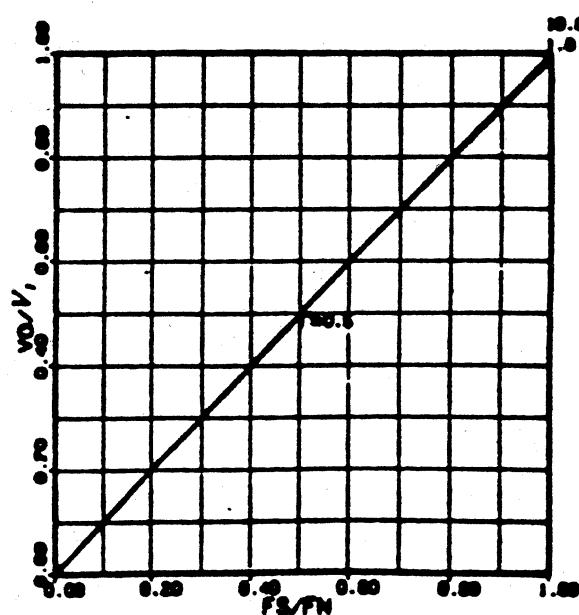


Ideal Waveforms

Operating Modes



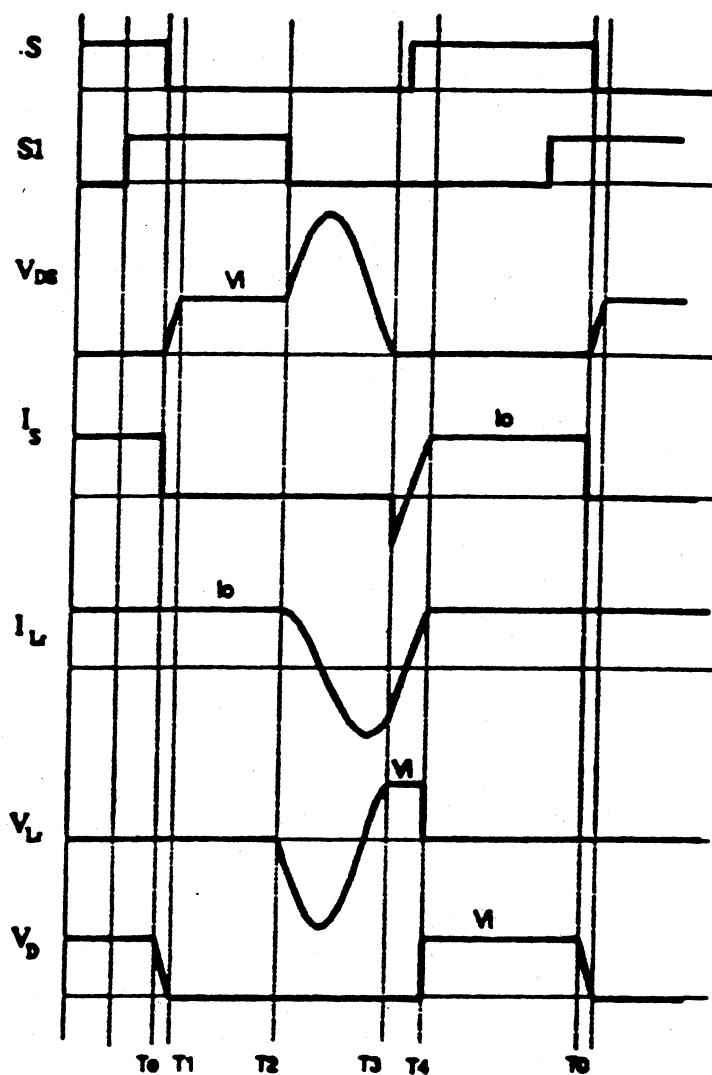
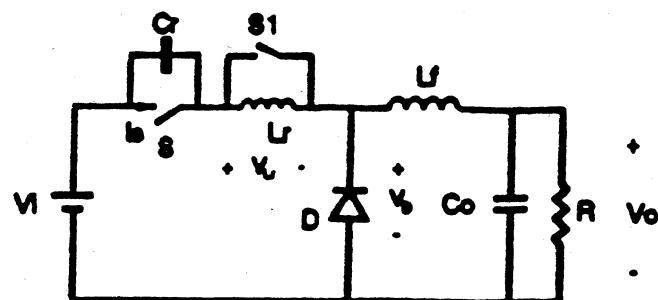
Waveforms at heavy, light loads



Control Characteristics

Figures from "High-Frequency Quasi-Resonant Converter Technologies" by F.C. Lee
Proc. IEEE, Vol. 76, No. 4, April 1988

ZVS PWM Buck Converter



Main Switch S:

ZVS Turn on, ZVS Turn off

Diode D:

ZVS Turn on, poor (high di/dt) ZCS turn off

Aux. Switch S1:

ZVS/ZCS Turn on, ZVS turn off

Figure from "An Overview of Soft-Switching Techniques for PWM Converters," by G. Hua and F.C. Lee, European Power Electronics Journal, Vol. 3, No. 1, March 1993.